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### Introduction

The field of photovoltaics has witnessed notable advancements, especially with the advent of three-dimensional (3D) hybrid halide perovskites. These materials offer adjustable band gaps, enhanced electron-hole diffusion lengths, low recombination rates, and cost-effective manufacturing. However, challenges such as device degradation due to environmental factors like oxygen and moisture persist.<sup>1-6</sup> In the face of these challenges, researchers have turned their attention to two-dimensional (2D) hybrid perovskites, inspired by the success of various 2D materials like transition metal dichalcogenides,<sup>7,8</sup> black phosphorus,<sup>9</sup> boron nitride (BN), and graphene.<sup>10</sup> These ultrathin 2D perovskites are currently being explored for applications in optoelectronics, including LEDs, FETs, and photodetectors. Building on experimental progress, significant theoretical

## Computational approaches to enhance charge transfer and stability in TPBi-(PEA)<sub>2</sub>Pbl<sub>4</sub> perovskite interfaces through molecular orientation optimization\*

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The optimization of material interfaces is crucial for the performance and longevity of optoelectronic devices. This study focuses on 1,3,5-tris(1-phenyl-1H-benzimidazol-2-yl)benzene (TPBi), a key component in perovskite devices known for its efficient charge transfer capabilities. We investigate the TPBi-(PEA)<sub>2</sub>Pbl<sub>4</sub> heterostructure interfaces to enhance device durability by optimizing interfacial properties. Our findings reveal that those specific TPBi orientations - at 15 and 30 degrees - ensure strong electronic coupling between TPBi and  $(PEA)_2PbI_4$ , which improves stability at these interfaces. Furthermore, orientations at 15 and 60 degrees markedly enhance charge transfer kinetics, indicating reduced recombination rates and potentially increased efficiency in optoelectronic devices. These results not only underscore the importance of molecular orientation in perovskite devices but also open new avenues for developing more stable and efficient hybrid materials in optoelectronic applications.

> investigations have delved into the electronic structures and optical characteristics of 2D perovskites. These studies suggest their high efficiency in absorption and photovoltaic applications, with performance variations based on their dimensional properties and inherent characteristics.<sup>11-16</sup> Notably, studies exemplify the potential of 2D perovskites, as demonstrated by Yang et al., who synthesized single-crystalline 2D perovskites using a colloidal method, confirming their suitability for optoelectronic detection devices.17-20

> In scientific discourse, there's an ongoing debate about the most effective use of 2D layered perovskites: should they be optimized for photovoltaic solar cells or optoelectronic detection devices? This study aims to clarify this issue, specifically focusing on the unique 2D layered phenylethylammonium (PEA) lead halide perovskite (PEA)<sub>2</sub>PbI<sub>4</sub>. The unique nature of 2D layered PEA lead halide perovskite stems from its distinctive structural and optoelectronic properties, setting it apart from other materials within the perovskite family. Structurally, PEA lead halide perovskite adopts a layered configuration, with organic phenylethylammonium cations sandwiched between inorganic lead halide layers. This 2D arrangement contrasts with the 3D structure commonly found in traditional perovskite materials, imparting flexibility and tunability to its properties. The incorporation of organic cations within the inorganic framework allows for precise control over its electronic band structure. Regarding optoelectronic properties, PEA perovskites exhibit intriguing behaviours such as tunable band gaps, strong light-matter interactions, and enhanced stability compared to

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their 3D counterparts.<sup>21–24</sup> This organic–inorganic hybrid nature enables them to serve as promising candidates for various optoelectronic applications.<sup>25,26</sup> Additionally, PEA lead halide perovskites demonstrate improved stability compared to purely inorganic perovskite counterparts, attributed to the mitigating effects of organic cations on defects and structural instabilities. Their enhanced stability contributes to improved material durability and performance under diverse environmental conditions. Furthermore, PEA perovskites are typically solutionprocessable, allowing seamless integration into thin-film optoelectronic devices through scalable and cost-effective manufacturing techniques. This solution processability, combined with their favourable optoelectronic properties, renders PEA perovskites attractive for large-scale applications such as solar cells, LEDs, and photodetectors.<sup>25,27,28</sup>

Through first-principle calculations, we meticulously examine the geometric and electronic properties of (PEA)<sub>2</sub>PbI<sub>4</sub>, paying particular attention to its charge transport characteristics and binding energy. Our primary objective is to develop a theoretical framework that offers valuable insights and potentially bridges the gap in the ongoing debate about the most advantageous applications of 2D perovskites in photovoltaics and optoelectronics. 2D perovskite materials, characterized by the chemical formula A2BX4, consist of stacked octahedral metal-halide (B-X) monolayers and are separated by long-chain organic molecules (A) to maintain charge balance.16,29,30 A notable feature of 2D hybrid perovskites, which sets them apart from their 3D counterparts, is their enhanced stability.<sup>31,32</sup> This stability is attributed mainly to the substantial van der Waals (vdW) interactions between the organic cations and inorganic anions, which help maintain the integrity of the 2D crystal structure. These materials also offer several distinct advantages, such as molecular-scale self-assembly, solution processability, excellent film formation capabilities, and remarkable optical properties characterized by extensive carrier diffusion lengths.33,34 However, challenges remain since the inclusion of an organic insulating layer in 2D perovskites can widen the energy band gap, increase exciton binding energy, and reduce optical absorption. These factors collectively present hurdles in achieving high energy conversion efficiency in 2D perovskite solar cells.<sup>23,35,36</sup> To improve the electronic structures and carrier transport properties of 2D perovskite, including aspects such as mobility, recombination, and the impact of molecular orientation on carrier properties, the design of vdW heterostructures<sup>37,38</sup> has been identified as a promising strategy. This development expands our ability to tailor specific electronic and optoelectronic properties.39,40 However, there remains a notable gap in both theoretical and experimental research regarding the photoelectric properties of vdW heterostructures that incorporate 2D perovskites, particularly when combined with TPBi (1,3,5-tris(1-phenyl-1H-benzimidazol-2-yl) benzene). Critical aspects, such as the energy band gap and band offsets within the TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructure, are yet to be fully explored despite their crucial importance in semiconductor heterostructure design.

A unique feature of TPBi is its remarkable orientation flexibility,<sup>41</sup> which can be skillfully leveraged to tailor photovoltaic

properties.42,43 The orientation of TPBi molecules within a device significantly affects charge transport characteristics, providing a means to mitigate the degradation of the emissive layer and improve overall device performance.44,45 This aspect is particularly vital given that crystal orientation is a crucial factor in the performance of multi-layer optoelectronic devices.46 Furthermore, the ability to manipulate molecular orientation offers a promising pathway to enhance charge carrier transfer within the charge transport layers. Such dynamics have the exciting potential to increase device efficiency, carrier mobility, and overall lifespan, marking a significant advancement towards the ideal optoelectronic device. The focal point of our research is the manipulation mechanism of molecular orientation at the interface between TPBi and perovskite materials. This aspect is instrumental in determining the efficiency, stability, and overall longevity of optoelectronic devices, and it plays a pivotal role in their potential for commercialization. Different molecular orientations can introduce specific changes in charge transfer properties,<sup>47</sup> a factor that could lead to the emergence of both energetic and positional disorders. These disorders have a significant impact on the characteristics of charge transport within the device.48

vdW interactions play a critical role in determining the orientations of TPBi molecules at the interface between TPBi and (PEA)<sub>2</sub>PbI<sub>4</sub> perovskite materials. These interactions encompass both attractive forces, such as dispersion forces, and repulsive forces arising from steric effects.49 The strength of these interactions is influenced by factors like molecular shape, size, and the distance between molecules. At the TPBi-(PEA)2-PbI<sub>4</sub> perovskite materials, London dispersion forces come into play due to the temporary fluctuations in electron cloud distributions, leading to attractive interactions.<sup>50</sup> The alignment of TPBi and (PEA)<sub>2</sub>PbI<sub>4</sub> perovskite materials, such as molecules in a way that minimizes repulsion and maximizes attractive forces, is dependent on the molecular geometry and electron distribution of each component. Achieving compatibility in molecular shape and electron density distribution optimizes vdW interactions, thereby reducing potential energy and facilitating favourable molecular orientations. This optimized arrangement enhances the efficiency of charge transfer and binding energy at the TPBi(PEA)<sub>2</sub>PbI<sub>4</sub> perovskite materials.<sup>51,52</sup> To precisely manipulate TPBi orientations in laboratory experiments, specific techniques are employed, including vapour deposition conditions that can be finely tuned to control TPBi deposition and interactions during the process. Controlled annealing, where temperature parameters are adjusted, allows for the reorganization of TPBi molecules to enhance interactions. Surface modification techniques, which involve altering either the substrate or the TPBi layer, can also be utilized to strengthen interactions. Leveraging van der Waals forces, the layer-by-layer assembly method creates well-defined interfaces. Additionally, external fields can induce the reorientation of TPBi molecules after fabrication to achieve preferred alignments.53-57 However, these endeavours are not without challenges. The properties of the substrate can influence the nature of forces and interactions taking place. The tendency of TPBi molecules to aggregate can impact the deposition process and subsequent interactions,

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necessitating careful consideration. Balancing thermal stability during annealing procedures is crucial to prevent molecular degradation and optimize interactions. Beyond van der Waals interactions, other forces such as electrostatic interactions and hydrogen bonding should be taken into account. Furthermore, the broader context of environmental impact and reproducibility in large-scale production introduces additional layers of complexity. Regarding the impact of molecular orientation on device performance, our ongoing experimental investigations aim to elucidate the correlation between molecular orientation and the efficiency, stability, and performance of perovskite solar cells. Preliminary results suggest that variations in TPBi molecular orientation can significantly affect charge transport characteristics, recombination dynamics, and overall device performance. For instance, devices with vertically aligned TPBi molecules exhibit enhanced charge extraction efficiency and reduced charge recombination rates, leading to improved photovoltaic performance and stability compared to devices with randomly oriented TPBi layers.

In our previous research,58 we concentrated on studying TPBi-FAPbI<sub>3</sub> heterostructures, highlighting the critical role of TPBi molecular orientation in affecting electronic band gaps and interfacial interactions. Building upon these findings, our current work focuses on TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures, delving into their unique electronic properties and charge transfer behaviours. This shift marks our continued dedication to broadening the scope of perovskite heterostructure research and deepening our understanding of this distinct system. Employing density functional theory (DFT), our latest study investigates TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> vdW heterostructures By manipulating the orientations of TPBi molecules, we achieve tunable band gaps, enhanced charge transport, and improved interfacial stability. These findings open promising avenues for developing low-dimensional optoelectronic devices. Supporting our theoretical predictions, recent experimental work<sup>59</sup> has successfully validated the complex interactions between TPBi and perovskite materials, setting an exciting groundwork for future advancements in optoelectronic device design.

### Theoretical methods

In this study, ab initio calculations were conducted to examine the impact of different orientations on the charge transfer characteristics at the interface and binding energy of the TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructure. These computational simulations were carried out employing the projector augmented wave (PAW) method within the framework of the Vienna ab initio simulation package (VASP) software.60 The molecular configuration of TPBi in isolation was constructed utilizing the Avogadro software.<sup>61</sup> Subsequently, structural optimization of TPBi was conducted, with the Perdew-Burke-Ernzerhof (PBE) exchange-correlation function,62 grounded in the generalized gradient approximation (GGA),63 implemented via the Gaussian 09 (ref. 64) software package to obtain the converged geometry. Regarding the (PEA)<sub>2</sub>PbI<sub>4</sub> structure, a relaxation procedure was implemented within the VASP environment, guaranteeing its aptness for the assembly of the intended heterostructures.

Density functional theory (DFT)^{65} calculations were performed utilizing the B3LYP functional^{66} along with a 6–31G(d,p) basis set.  $^{67}$ 

## **Results and discussion**

At the TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> interface, we examined TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures with six different TPBi orientations. Initial distances between the nearest TPBi atom and (PEA)<sub>2</sub>PbI<sub>4</sub> atom were 2 Å due to vdW interactions. However, these distances exhibited variations after relaxation, as outlined in Table S1.<sup>†</sup> This interaction induced structural distortion at the (PEA)<sub>2</sub>PbI<sub>4</sub> surface, as shown in Fig. 1. Using optimized structures, we analysed binding energy, electron density, charge distribution, and charge transfer parameters. The detailed results are provided in the ESI Section,<sup>†</sup> with a visual representation of binding energy variations presented in Trend Fig. S1.<sup>†</sup>

We conducted a comprehensive analysis of the density of states (DOS) (Fig. 2) and projected density of states (PDOS) (Fig. 3). DOS analysis revealed that varied TPBi orientations influence the electronic bandgap. Examining DOS profiles allowed the identification of additional electronic states resulting from interface hybridization in different orientations. Total density of state (TDOS) plots for various TPBi orientations (0-degree, 15-degree, 30-degree, 45-degree, 60-degree, and 90-degree) are shown in Fig. S2(a–f).† These plots offer side-by-side comparisons of TDOS profiles of (PEA)<sub>2</sub>PbI<sub>4</sub> and the specific TPBi–(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructure, facilitating meaningful comparisons. The black dashed line, representing the Fermi level, divides TDOS profiles into valence and conduction bands on the left and right, respectively.

Our findings confirm that changes in TPBi orientation trigger pronounced charge redistribution due to charge hybridization at the interface. This interaction results in the emergence of interfacial states, leaving a distinct mark on the TDOS profiles of TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures, differentiating them from the TDOS of (PEA)<sub>2</sub>PbI<sub>4</sub>. In our study of TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures, we examined the variations in HOMO and LUMO energy levels across different orientations. Detailed bandgap values for all TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures are compiled in Table S2.† Remarkably, despite significant disparities in HOMO and LUMO values as well as the bandgap, both the 15-degree and 60-degree orientations yield approximately similar charge transfer values. The 15-degree orientation registers the highest charge transfer value of 0.403 e, while the 60-degree orientation records a charge transfer value of 0.401 e. This intriguing observation suggests that the strategic choice of TPBi orientation may effectively alleviate disparities in charge transport characteristics. Notably, TPBi orientation emerges as a pivotal factor influencing this intricate process. The observed equilibrium in charge transport efficiency across diverse orientations strongly implies the substantial involvement of additional factors, including carrier mobility, interfacial states, and energy barriers, in shaping these dynamic phenomena.

Expanding upon our analysis of the TDOS, the PDOS analysis allows us to delve deeper into the intricate contributions of



Fig. 1 Relaxed TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures with (a) 0-degree, (b) 15-degree, (c) 30-degree, (d) 45-degree, (e) 60-degree, (f) 90-degree orientation of TPBi.



Fig. 2 DOS profile of TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures.

individual orbitals to the formation of the valence and conduction bands in TPBi–(PEA)<sub>2</sub>PbI<sub>4</sub> and (PEA)<sub>2</sub>PbI<sub>4</sub>, while considering their HOMO and LUMO levels. Fig. 3(a–f) presents the PDOS profiles of selected TPBi orientations for TPBi–(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures, offering a view of the specific orbital contributions. At the same time, Fig. S3<sup>+</sup> focuses on

(PEA)<sub>2</sub>PbI<sub>4</sub>, giving insight into the role of pseudo-electrons associated with each constituent element in shaping these bands. What's particularly interesting is the composition of the valence band, where the dominant contributions in TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures come from the 2p-orbitals of Carbon (C) and Nitrogen (N) atoms. Following closely are the 5p-orbitals of Iodine (I) atoms, which also contribute substantially to the valence band formation. These contributions play a significant role in defining the electronic structure of the valence band. The energy levels of these contributions are associated with the HOMO levels of the material. In a sharp departure, Fig. S3<sup>†</sup> presents a distinct scenario within (PEA)<sub>2</sub>-PbI<sub>4</sub>, where the primary influence on shaping the valence band is attributed to the 5p-orbitals of I atoms and 6s-orbitals of Lead (Pb) atoms situated in proximity to the Fermi level. These I and Pb orbitals exert a substantial impact on the HOMO level of (PEA)<sub>2</sub>PbI<sub>4</sub> and play a crucial role in defining its electronic characteristics. Moreover, a subtle hybridization exists with the 2p-orbitals of C atoms at an energy level near -2 eV. The lower energy levels within the valence band of (PEA)<sub>2</sub>PbI<sub>4</sub> are markedly influenced by the hybridization of diverse orbitals. This encompasses the blending of 2p-orbitals from C atoms and 2porbitals originating from N atoms, in conjunction with the 1sorbitals associated with hydrogen (H) atoms. These orbital



Fig. 3 PDOS for (a) 0-degree, (b) 15-degree, (c) 30-degree, (d) 45-degree, (e) 60-degree, (f) 90-degree orientation of TPBi.

interactions give rise to the formation of electronic states situated within the lower energy range of the valence band, thus contributing to the overall electronic structure of  $(PEA)_2PbI_4$ , including the determination of its HOMO level. Conversely, the LUMO level correlates with the energy levels residing in the conduction band. The evaluation of the electronic structure and the contributions from distinct orbitals to the conduction band in both TPBi-(PEA)\_2PbI\_4 and  $(PEA)_2PbI_4$  would conform to a comparable analytical framework, thereby shedding light on the LUMO levels of these materials.

Shifting our focus to the formation of the conduction band reveals the pivotal roles specific orbitals play in shaping electronic states across varying energy levels. Notably, the 6sorbitals of Pb atoms take centre stage in defining states at lower energy levels within the conduction band. These Pb 6sorbitals exhibit robust hybridization with the 2p-orbitals of C atoms, giving rise to electronic states that significantly influence the lower energy range of the conduction band. In contrast, the 2p-orbitals of C and N atoms and the 5p-orbitals of I atoms make comparatively modest contributions to the higher energy range of the conduction band. A crucial observation arises when comparing the PDOS profiles of TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures in Fig. 3(a-f) with the DOS of  $(PEA)_2PbI_4$ featured in Fig. S3.<sup>†</sup> Notably, the prominent peaks on the valence band side in TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures can be primarily attributed to the 5p-orbitals of I atoms within (PEA)<sub>2</sub>PbI<sub>4</sub>, particularly in the vicinity of the Fermi level. Furthermore, there is a modest contribution from the hybridized states of 2p-orbitals of C and N atoms from TPBi. It is evident that TPBi strongly influences the DOS, which is clearly highlighted by comparing the results of TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures shown in Fig. S2(a–f).† Similarly, the significant peaks near the Fermi level on the conduction band side of TPBi–(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures are primarily due to the 6p orbitals of Pb atoms within (PEA)<sub>2</sub>PbI<sub>4</sub>. These 6p orbitals are complemented by the hybridization of 2p-orbitals of C and N atoms from both (PEA)<sub>2</sub>PbI<sub>4</sub> and TPBi. Collectively, these detailed PDOS profiles reveal the profound impact of TPBi orientation on interfacial hybridizations within TPBi–(PEA)<sub>2</sub>-PbI<sub>4</sub> heterostructures. This, in turn, significantly influences the DOS and leads to noteworthy alterations in electronic properties and charge transfer behaviour within the TPBi–(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructure.

To delve deeper into the charge transfer characteristics of heterostructures, we've depicted the isosurface charge density difference using Bader charge analysis in Fig. 4. This figure illustrates the distribution of charges within the Bader volume associated with specific atoms, thereby revealing the total charge carried by each atom. A positive Bader value indicates a decrease in charge carriers, whereas a negative value indicates an increase in charge carriers. In our prior investigation centred on TPBi-FAPbI<sub>3</sub> heterostructures,<sup>58</sup> our Bader charge analysis consistently revealed a distinct charge depletion pattern at C and Pb atoms, indicative of their cationic nature. Meanwhile, N, I, and H atoms consistently demonstrated charge accumulation. It's noteworthy that in our previous research, TPBi-FAPbI<sub>3</sub> highlighted a significant finding - an average charge transfer of 0.570 e for the 15-degree orientation, confirming excellent efficiency in electron transport at the interface. Our recent study focusing on TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructures showed a distinctive charge depletion at both C and Pb atoms, indicating their cationic nature. Conversely, there is a consistent



Fig. 4 Bader Charge analysis of TPBi molecule at (a) 0-degree, (b) 15-degree, (c) 30-degree, (d) 45-degree, (e) 60-degree, and (f) 90-degree orientation at the surface of (PEA)<sub>2</sub>PbI<sub>4</sub>.

accumulation of charge at N and H atoms. An intriguing observation arises as we identified anomalous behaviours of I atoms through Bader charge analysis. Upon careful examination (Fig. 4), we observed that the corresponding charge transfer value is lower when the I atom carries a more negative or a less positive charge in specific orientations. Conversely, the charge transfer is higher in orientations where the positive charge is higher, or the negative charge is lower. Notably, in the case of a 60-degree orientation, the H atoms exhibited a substantial positive charge. This observation elucidates why the charge transfer for the 60-degree orientation is roughly equivalent to that of the 15-degree orientation. Remarkably, this observation consistently aligns with our findings from PDOS results, underscoring the significant contribution of I atoms to the formation of the valence band. Our latest research emphasizes the enduring importance of TPBi orientations in enhancing charge transfer within TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> interfaces, providing insightful distinctions in charge transfer properties compared to TPBi-FAPbI3 heterostructures.

Isosurface analysis offers a detailed examination of charge density distributions and their variations within a given volume. This technique involves the generation of threedimensional surfaces that represent regions of constant charge density, providing a visual representation of electron distribution and indicating the charge transfer phenomena occurring within complex heterostructures. In this study, we utilize isosurface analysis to explore the charge transfer characteristics of heterostructures, unravelling subtle nuances in charge dynamics and enhancing our understanding of the material's electronic behaviour. Fig. 5(a-f) visually represents these assessments for various TPBi orientations (0-degree, 15degree, 30-degree, 45-degree, 60-degree and 90-degree). To visualize these distinctive features, we harnessed the capabilities of the Vesta software package.<sup>68</sup> An isosurface value of 0.0002 was thoughtfully selected, complemented by a section opacity set at 0% to provide a crystal-clear view. In this visual representation, the red regions clearly outline areas of charge accumulation, while the green regions showcased in Fig. 5 serve as a compelling visual testament to the depletion of charge carriers. These graphical depictions underscore that the interface experiences the lowest charge transfer when TPBi is oriented at 90-degree. In stark contrast, the most rapid charge transfer is observed when TPBi is inclined at a 15-degree and 60degree angle concerning (PEA)<sub>2</sub>PbI<sub>4</sub>. The charge transfer rate



**Fig. 5** Isosurface charge density at  $(0\ 1\ 0)$  surface of  $(PEA)_2PbI_4$  with (a) 0-degree, (b) 15-degree, (c) 30-degree, (d) 45-degree, (e) 60-degree, (f) 90-degree orientation of TPBi.

shows a progressive increase with shifts in TPBi orientation, following the sequence of 90-degree, 0-degree, 45-degree, 30-degree, 60-degree, and 15-degree. This variation in the rate of vdW interactions for different orientations of the TPBi-(PEA)<sub>2</sub>-PbI<sub>4</sub> heterostructure implies heightened atomic layer interactions within the heterostructure, which could plausibly elucidate the observed differences in charge transfer dynamics.

To comprehensively understand the surface characteristics of the TPBi layer and the underlying mechanisms governing charge transport at the interfaces, we present visual representations in Fig. 6 and 7, showcasing the averaged charge density and integrated charge density difference along the z-axis respectively. For a detailed examination of the individual heterostructures, please refer to Fig. S4 and S5,† which provide the averaged charge density and integrated charge density difference along the z-axis for each of the six orientations (0-degree, 15-degree, 30-degree, 45-degree, 60-degree, and 90-degree). Our average charge density data encompasses both positive and negative values, shedding light on the spatial distribution of electrons at specific z (Å) positions. Notably, we observe prominent peaks within the z-range of 0 Å to 16 Å, indicating a significant electron density within the initial three atomic layers of (PEA)<sub>2</sub>PbI<sub>4</sub>, a characteristic feature of perovskite materials. However, as we extend the analysis beyond the 16 Å zvalue, the final peak exhibits a relatively lower intensity, corresponding to the TPBi layer. A compelling point of contrast arises when comparing these findings to our prior research on FAPbI<sub>3</sub>, where we considered a broader z-range (0 Å to 27 Å). This significant variation accentuates the material-specific disparities in electron distribution at the interfaces. To bridge these analyses, we explore the comparison with TPBi-FAPbI3 interfaces, shedding light on material-specific disparities in electron distribution at the interfaces.

Compared to the TPBi–FAPbI<sub>3</sub> interfaces, a sharp decline in charge density in the TPBi–(PEA)<sub>2</sub>PbI<sub>4</sub> interfaces suggests a limited number of electrons, attributed to intricate electronic charge hybridization. As shown in Fig. S6,† in the TPBi–(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructure, the surface of (PEA)<sub>2</sub>PbI<sub>4</sub> displays only I atoms, and their proximity to TPBi is greater than



Fig. 6 Charge density of TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> interfaces.

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Fig. 7 Charge density difference coupling with Bader charge analysis.

that to Pb atoms. In contrast, in the TPBi-FAPbI<sub>3</sub> heterostructure, both I and Pb atoms are present on the surface of FAPbI<sub>3</sub>, fostering easier interaction with TPBi. This difference in the proximity of Pb and I atoms influences the ease of interaction with TPBi. Upon comparing the 15-degree orientation for both heterostructures, it is evident that in the TPBi-FAPbI<sub>3</sub> case, the charge transfer value is higher than the TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructure. This discrepancy can be attributed to the presence of both I and Pb atoms on the surface of FAPbI<sub>3</sub>, facilitating a more efficient charge transfer interaction with TPBi. Interestingly, in the TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> heterostructure, an approximately equal charge transfer is observed for 15-degreeand 60-degree orientations. Notably, these nearly identical charge transfer values suggest a unique behaviour, underscoring the collective influence of I and Pb atoms in facilitating charge transfer. This observation suggests a unique behaviour, indicating that I and Pb atoms collectively play a crucial role in charge transfer in this heterostructure. This is supported by the significant contribution of 5p-orbitals of I atoms to valence band formation and 6p-orbitals of Pb atoms to the conduction band. The distinctive charge transfer behaviour TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> highlights the nuanced interplay of atomic interactions, providing valuable insights into the material's electronic structure and charge transfer dynamics. These pronounced distinctions in charge transfer behaviour between TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> and TPBi-FAPbI<sub>3</sub> shed light on the intricate interplay of atomic interactions. These insights contribute to a deeper understanding of the electronic properties and transport dynamics at the interfaces, offering valuable knowledge for the development of advanced material systems.

Likewise, the integrated charge density difference curve along the *z*-axis provides a quantitative perspective on charge transfer along this axis. As illustrated in Fig. 7, this curve reveals the charge transfer dynamics at the TPBi–(PEA)<sub>2</sub>PbI<sub>4</sub> interface, offering insights into the charge accumulation and depletion between both layers. The interface region, delineated in Fig. 7, further highlights the nuanced variations in charge distribution. The interface region in Fig. 7 provides an estimation for all orientations, encapsulating the comprehensive charge transfer

phenomena at the TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> interface. The observed behaviour in Fig. 7 strikingly aligns with the patterns of accumulation and depletion identified in the Bader charge analysis, as depicted in Fig. 4. Specifically, I atoms at the surface of  $(PEA)_2PbI_4$  are seen to deplete charges, while accumulation occurs at the nearby C atoms of TPBi. Furthermore, N atoms in TPBi also exhibit a significant accumulation of electrons. For a more detailed examination of the individual heterostructures, please refer to Fig. S5.† In Fig. S5,† the interface region for each structure is individually showcased, revealing a finer granularity of the charge transfer dynamics. Each structure's interface region is further divided into two distinct parts: accumulation and depletion. The accumulation regions are vividly marked in red, indicating areas where charge carriers gather, while the depletion regions are distinctly marked in green, representing zones where charge carriers are diminished. This detailed breakdown in Fig. S5<sup>†</sup> offers a comprehensive view of how each orientation contributes to the overall charge transfer dynamics. The intensity of the peaks, signifying accumulation and depletion, reinforces the earlier predictions regarding the 15-degree and 60-degree structures having the highest charge transfer efficiency, as previously suggested in the Bader charge analysis sections. These findings provide a comprehensive understanding of the charge transfer dynamics occurring at the TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> interface, supporting the idea that specific TPBi orientations play a pivotal role in governing these interactions.

The averaged electrostatic potential along the *z*-axis is a valuable tool for elucidating crucial aspects of charge transfer characteristics, discerning the presence of electrons and holes at specific *z*-values. This potential provides a comprehensive profile of the electric charge distribution at different positions along the *z*-axis. The charge transfer process is intrinsically linked to the potential difference; electrons exhibit migration from regions characterized by low potential to those with higher potential, whereas holes traverse from areas of high potential to lower potential. Fig. 8 delineates electrostatic potential profiles for TPBi orientations on the (PEA)<sub>2</sub>PbI<sub>4</sub> surface, with an estimated interface region and vacuum energy ( $E_{vac}$ ) level depicted



Fig. 8 Average electrostatic potential along the z-axis.

for all orientations. Concurrently, Fig. S7<sup>†</sup> elucidates the respective electrostatic potential profiles corresponding to each TPBi orientation on the  $(PEA)_2PbI_4$  surface, providing a detailed breakdown for each individual orientation, including the estimated interface region and  $E_{vac}$  level. The data presented in the figures constitute a pivotal facet of the inquiry into the intermolecular forces and electronic interactions dictating the TPBi–(PEA)\_2PbI\_4 interface, furnishing valuable insights for a broader comprehension of the scrutinized system.

Significantly, the electrostatic potential profiles exhibit prominent negative peaks, signalling the substantial presence of electrons within (PEA)<sub>2</sub>PbI<sub>4</sub>. This observation is consistent with the findings from the averaged charge density plot, as illustrated in Fig. 6. A discernible rise in the electrostatic potential becomes apparent upon entering the region where TPBi is situated within each heterostructure. This noticeable increase implies a highly favourable propensity for electron transfer from  $(PEA)_2PbI_4$  to TPBi within these regions. Furthermore, positive potential values substantiate the depletion of charges from TPBi to (PEA)<sub>2</sub>PbI<sub>4</sub>, aligning seamlessly with the insights outlined in the description of the isosurface charge density analysis. Therefore, these electrostatic potential profiles offer crucial insights into the dynamics of charge transfer between (PEA)<sub>2</sub>PbI<sub>4</sub> and TPBi across the various orientations considered in our study.

#### Conclusions

Our study underscores the significant impact of molecular orientation on the efficiency, stability, and performance of perovskite devices, particularly evident at TPBi-(PEA)<sub>2</sub>PbI<sub>4</sub> interfaces as determined through computational methods. Key findings include the effect of TPBi orientation at 15 and 60 degrees on charge transfer dynamics, where optimal orientations enhance device efficiency. Binding energy calculations offer insights into device stability, with the most stable structures at the 15 and 30-degree TPBi orientations. These findings are further substantiated by Bader charge, charge density, and isosurface analysis, which collectively confirm effective charge transfer mechanisms. This study highlights the role of interfacial molecular orientation in optimizing perovskite device performance and contributes to the development of lowdimensional optoelectronic devices, tapping into the full potential of perovskite materials for efficient and sustainable optoelectronics.

#### Author contributions

S. Chang and Y. Zhu conceived and directed the project; S. M. K. A. Naqvi, H. Long, Z. Nazir and Y. Zhu prepared the models, carried out the simulations and prepared the figures; S. M. K. A. Naqvi, R. B. Vasiliev, O. Kulakovich and S. Chang analysed the data, interpreted the results and wrote the manuscript.

#### Conflicts of interest

The authors declare no conflicts of interest.

#### Paper

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